## Features

- Noise Figure: 2.7 dB Typical
- Gain: 15.5 dB Typical
- Single Bias Supply
- Low Current Consumption
- DC Decoupled RF Input and Output
- Ceramic Package


## Description

M/A-COM's MAAM71200-H1 is a wide band, low noise GaAs MMIC amplifier enclosed in a leadless ceramic package. The MAAM71200-H1 is a packaged version of M/A-COM's MAAM71200 low noise MMIC amplifier chip. The fully monolithic design operates in 50 ohms without the need for external components.

The MAAM71200-H1 is ideally suited for microstrip assemblies where wire or ribbon bonds are used for interconnects. Typical applications include radar, EW and communication systems.

The MAAM71200-H1 is fabricated using a mature 0.5 -micron gate length GaAs process for increased


## Functional Diagram



1. Case must be electrically connected to RF and DC ground.
2. The RF bond inductance from the transmission line to the package is assumed to be 0.25 nH . Variations in bond inductance will result in variations in VSWR and gain slope. A small capacitive stub may be needed depending on the inductance realized in the final assembly.
3. Nominal bias is obtained by setting $\mathrm{V}_{\mathrm{DD}}=4 \mathrm{~V}$.
4. Increasing $\mathrm{V}_{\mathrm{DD}}$ from 4 volts to 6 volts increases output power and high frequency bandwidth.

Absolute Maximum Ratings ${ }^{5,6}$

| Parameter | Absolute Maximum |
| :---: | :---: |
| Input Power | +20 dBm |
| $\mathrm{V}_{\mathrm{DD}}$ | +7 V |
| Junction Temperature | $+150^{\circ} \mathrm{C}$ |
| Thermal Resistance | $+175^{\circ} \mathrm{C} / \mathrm{W}$ |
| Storage Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |

5. Exceeding any one or combination of these limits may cause permanent damage to this device.
6. M/A-COM does not recommend sustained operation near these survivability limits.

## Handling Procedures

Please observe the following precautions to avoid damage:

## Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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Electrical Specifications: $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=4 \mathrm{~V}$


- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit ww.macomtech.com for additional data sheets and product information.


## Typical Performance Curves

## Gain <br> 

Input and Output VSWR


## Noise Figure



Output Power @ 1 dB Compression


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